

Special Issue on Optoelectronic Neuromorphic Devices

Guest editors: Zhenyi Ni, Zhongqiang Wang, Jia Huang, and Xiaodong Pi

■ EDITORIAL

020101 **Preface to Special Issue on Optoelectronic Neuromorphic Devices**

[3 pages] Zhenyi Ni, Zhongqiang Wang, Jia Huang, and Xiaodong Pi

■ SPECIAL ISSUE REVIEWS

021401 **Electrolyte-gated optoelectronic transistors for neuromorphic applications**

[17 pages] Jinming Bi, Yanran Li, Rong Lu, Honglin Song, and Jie Jiang

021402 **Ion-modulation optoelectronic neuromorphic devices: mechanisms, characteristics, and applications**

[13 pages] Xiaohan Meng, Runsheng Gao, Xiaojian Zhu, and Run-Wei Li

021403 **Synaptic devices based on silicon carbide for neuromorphic computing**

[14 pages] Boyu Ye, Xiao Liu, Chao Wu, Wensheng Yan, and Xiaodong Pi

021404 **Adaptive optoelectronic transistor for intelligent vision system**

[18 pages] Yiru Wang, Shanshuo Liu, Hongxin Zhang, Yuchen Cao, Zitong Mu, Mingdong Yi, Linghai Xie, and Haifeng Ling

021405 **Recent progress in organic optoelectronic synaptic transistor arrays: fabrication strategies and innovative applications of system integration**

[15 pages] Pu Guo, Junyao Zhang, and Jia Huang

■ SPECIAL ISSUE ARTICLES

022401 **Deep-UV-photo-excited synaptic Ga₂O₃ nano-device with low-energy consumption for neuromorphic computing**

[9 pages] Liubin Yang, Xiushuo Gu, Min Zhou, Jianya Zhang, Yonglin Huang, and Yukun Zhao

022402 **Electropolymerized dopamine-based memristors using threshold switching behaviors for artificial current-activated spiking neurons**

[6 pages] Bowen Zhong, Xiaokun Qin, Zhixin Li, Yiqiang Zheng, Lingchen Liu, Zheng Lou, and Lili Wang

022403 **Visual synapse based on reconfigurable organic photovoltaic cell**

[8 pages] Xiangrong Pu, Fan Shu, Qifan Wang, Gang Liu, and Zhang Zhang

022404 **Nanowatt-level optoelectronic GaN-based heterostructure artificial synaptic device for associative learning and neuromorphic computing**

[7 pages] Teng Zhan, Jianwen Sun, Jin Lin, Banghong Zhang, Guanwan Liao, Zewen Liu, Junxi Wang, Jinmin Li, and Xiaoyan Yi

022405 **All-optical nonlinear activation functions realized on phase-change photonic integrated circuits with microheaters**

[10 pages] Jiyuan Jiang, Bingxin Ding, Shiyu Li, Xin Zhang, Haihua Wang, Jie Wu, Xiaoyan Liu, Zhou Wang, Xiaojuan Lian, Wen Huang, and Lei Wang

022406 **Reconfigurable organic ambipolar optoelectronic synaptic transistor for information security access**

[10 pages] Xinqi Ma, Wenbin Zhang, Qi Zheng, Wenbiao Niu, Zherui Zhao, Kui Zhou, Meng Zhang, Shuangmei Xue, Liangchao Guo, Yan Yan, Guanglong Ding, Suting Han, Vellaisamy A. L. Roy, and Ye Zhou

022407 **Optoelectronic memristor based on a-C:Te film for multi-mode reservoir computing**

[6 pages] Qiaoling Tian, Kuo Xun, Zhuangzhuang Li, Xiaoning Zhao, Ya Lin, Ye Tao, Zhongqiang Wang, Daniele Ielmini, Haiyang Xu, and Yichun Liu

■ **ARTICLES**

022501 **6-inch AlN epitaxial films with low dislocation densities via MOCVD**

[7 pages] Shunpeng Lu, Jianwei Ben, Ke Jiang, Shanli Zhang, Ruoqia Zhang, Jialong Hao, Zhongxu Liu, Wenchao Sun, Zikai Nie, Xiaojuan Sun, and Dabing Li

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